

isc N-Channel MOSFET Transistor

IRFR540Z, IIRFR540Z

• FEATURES

- Static drain-source on-resistance:
 R_{DS}(on)≤28.5mΩ
- Enhancement mode:
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

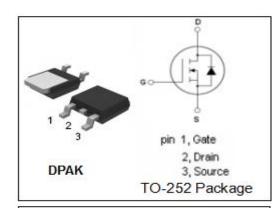
· Fast switching

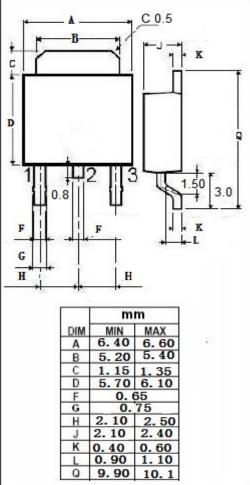
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL | PARAMETER | VALUE | UNIT | |
|------------------|--|---------|--------------|--|
| V _{DSS} | Drain-Source Voltage | 100 | V | |
| V_{GS} | Gate-Source Voltage | ±20 | V | |
| I _D | Drain Current-Continuous | 35 | А | |
| I _{DM} | Drain Current-Single Pulsed | 140 | А | |
| P _D | Total Dissipation @T _C =25℃ | 91 | W | |
| Tj | Max. Operating Junction Temperature | 175 | $^{\circ}$ C | |
| T _{stg} | Storage Temperature | -55~175 | $^{\circ}$ | |

• THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT |
|----------|---------------------------------------|------|------|
| Rth(j-c) | Channel-to-case thermal resistance | 1.64 | °C/W |
| Rth(j-a) | Channel-to-ambient thermal resistance | 110 | °C/W |







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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | ТҮР | MAX | UNIT |
|---------------------|--------------------------------|--|-----|-----|------|------|
| BV _{DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V; I _D =250 μ A | 100 | | | V |
| V _{GS(th)} | Gate Threshold Voltage | VDS=VGS; I _D =50 μ A | 2 | | 4 | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} =10V; I _D =21A | | | 28.5 | mΩ |
| I _{GSS} | Gate-Source Leakage Current | V _{GS} = ±20V | | | ±0.2 | μА |
| I _{DSS} | Drain-Source Leakage Current | V _{DS} =100V; V _{GS} = 0V | | | 20 | μА |
| V _{SD} | Diode forward voltage | I _s =21A, V _{GS} = 0V | | | 1.3 | V |

NOTICE:

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